

# SKYPER 32 PRO R



SKYPER®

## IGBT Driver Core

### SKYPER 32 PRO R

#### Preliminary Data

#### Features

- Two output channels
- Integrated potential free power supply
- Under voltage protection prim/sec
- Drive interlock top / bottom
- Dynamic short circuit protection
- Halt status with failure management
- External failure input (sec.)
- Soft turn-off
- UL recognized, ROHS
- IEC 60068-1 (climate) 40/085/56, no condensation and no dripping water permitted, non-corrosive, climate class 3K3 acc. EN60721
- Coated with varnish

#### Typical Applications\*

- Driver for IGBT modules in bridge circuits in industrial application
- DC bus voltage up to 1200V

#### Footnotes

with external high voltage diode  
Please Note: the isolation test is not performed as a series test at SEMIKRON and must be performed by the user according to VDE 0110-20

Isolation coordination in compliance with EN50178 PD2  
Operating temperature is real ambient temperature around the driver core  
Degree of protection: IP00

Driver Core

Absolute Maximum Ratings			
Symbol	Conditions	Values	Unit
$V_s$	Supply voltage primary	16	V
$V_{iH}$	Input signal voltage (HIGH)	$V_s + 0.3$	V
$V_{iL}$	Input signal voltage (LOW)	GND - 0.3	V
$I_{outPEAK}$	Output peak current	15	A
$I_{outAVmax}$	Output average current	50	mA
$f_{max}$	Max. switching frequency	50	kHz
$V_{CE}$	Collector emitter voltage sense across the IGBT	1700	V
dv/dt	Rate of rise and fall of voltage secondary to primary side	50	kV/ $\mu$ s
$V_{isolIO}$	Isolation test voltage input - output (AC, rms, 2s)	4000	V
$V_{isolPD}$	Partial discharge extinction voltage, rms, $Q_{PD} \leq 10pC$	1500	V
$V_{isol12}$	Isolation test voltage output 1 - output 2 (AC, rms, 2s)	1500	V
$R_{Gon\ min}$	Minimum rating for external $R_{Gon}$	1.5	$\Omega$
$R_{Goff\ min}$	Minimum rating for external $R_{Goff}$	1.5	$\Omega$
$Q_{out/pulse}$	Max. rating for output charge per pulse	6.3	$\mu$ C
$T_{op}$	Operating temperature	-40 ... 85	$^{\circ}$ C
$T_{stg}$	Storage temperature	-40 ... 85	$^{\circ}$ C

Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
$V_s$	Supply voltage primary side	14.4	15	15.6	V
$I_{SO}$	Supply current primary (no load)		80		mA
	Supply current primary side (max.)			500	mA
$V_i$	Input signal voltage on / off		15 / 0		V
$V_{IT+}$	Input treshold voltage HIGH			12.3	V
$V_{IT-}$	input threshold voltage (LOW)	4.6			V
$R_{iN}$	Input resistance (switching/HALT signal)		100		k $\Omega$
$V_{G(on)}$	Turn on output voltage		15		V
$V_{G(off)}$	Turn off output voltage		-7		V
$f_{ASIC}$	Asic system switching frequency		8		MHz
$t_{d(on)O}$	Input-output turn-on propagation time		1.2		$\mu$ s
$t_{d(off)O}$	Input-output turn-off propagation time		1.2		$\mu$ s
$t_{d(err)}$	Error input-output propagation time	3.1		5.8	$\mu$ s
$t_{pERRRESET}$	Error reset time		9		$\mu$ s
$t_{TD}$	Top-Bot interlock dead time	0		4.3	$\mu$ s
$C_{ps}$	Coupling capacitance prim sec		12		pF
w	weight		34		g
MTBF			1.3		$10^6$ h

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.

## Technical Explanations

Revision 04  
Status:  
Prepared by: Johannes Krapp

*This Technical Explanation is valid for the following parts:*

*Related Documents:*

<i>part number:</i>	L6100202	<i>title:</i>	Data Sheet SKYPER 32PRO R
<i>date code (YYWW):</i>	≥ CW22 2014		

# SKYPER® 32PRO R

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**Please note:**

Unless otherwise specified, all values in this technical explanation are typical values. Typical values are the average values expected in large quantities and are provided for information purposes only. These values can and do vary in different applications. All operating parameters should be validated by user's technical experts for each application.

## Application and Handling Instructions

- Please provide for static discharge protection during handling. As long as the hybrid driver is not completely assembled, the input terminals have to be short-circuited. Persons working with devices have to wear a grounded bracelet. Any synthetic floor coverings must not be statically chargeable. Even during transportation the input terminals have to be short-circuited using, for example, conductive rubber. Worktables have to be grounded. The same safety requirements apply to MOSFET- and IGBT-modules.
- Any parasitic inductances within the DC-link have to be minimised. Over-voltages may be absorbed by C- or RCD-snubbers between main terminals for PLUS and MINUS of the power module.
- When first operating a newly developed circuit, SEMIKRON recommends to apply low collector voltage and load current in the beginning and to increase these values gradually, observing the turn-off behaviour of the free-wheeling diode and the turn-off voltage spikes generated across the IGBT. An oscillographic control will be necessary. Additionally, the case temperature of the module has to be monitored. When the circuit works correctly under rated operation conditions, short-circuit testing may be done, starting again with low collector voltage.
- It is important to feed any errors back to the control circuit and to switch off the device immediately in failure events. Repeated turn-on of the IGBT into a short circuit with a high frequency may destroy the device.
- The inputs of the hybrid driver are sensitive to over-voltage. Voltages higher than  $V_S + 0,3V$  or below  $-0,3V$  may destroy these inputs. Therefore, control signal over-voltages exceeding the above values have to be avoided.
- The connecting leads between hybrid driver and the power module should be as short as possible (max. 20cm), the driver leads should be twisted.

## UL specified remarks

- The equipment shall be installed in compliance with the mounting and spacing requirements of the end-use application.
- SKYPER 32 shall be supplied by an isolated limited voltage / limited current source or a Class 2 source. The 15 A peak rating is an instantaneous peak rating only.
- These devices do not incorporate solid-state motor overload protection. The need for overload protection and over-current protection devices shall be determined in the end-use product.
- These devices have not been evaluated to over-voltage, over-current, and over-temperature control, and may need to be subjected to the applicable end-product tests.
- Temperature and tests shall be considered in the end use. Due to the limited current source, only the effect of heat generating components in this device on adjacent components in the end product needs to be considered.
- Connectors have not been evaluated field wiring; all connections are to be factory wired only.

## Further application support

Latest information is available at <http://www.semikron.com>. For design support please read the SEMIKRON Application Manual Power Modules available at <http://www.semikron.com>.

## General Description

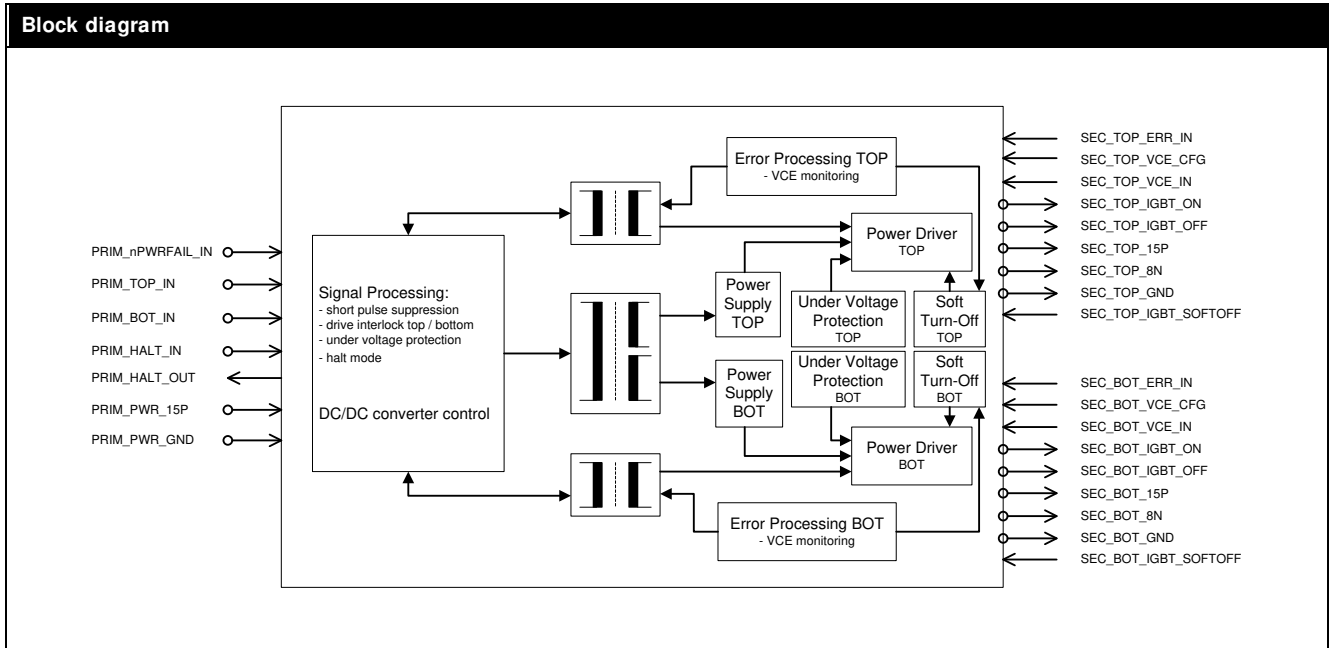
The SKYPER 32PRO core constitutes an interface between IGBT modules and the controller. This core is a half bridge driver. Functions for driving, potential separation and protection are integrated in the driver. Thus it can be used to build up a driver solution for IGBT modules.

## Features of SKYPER 32PRO

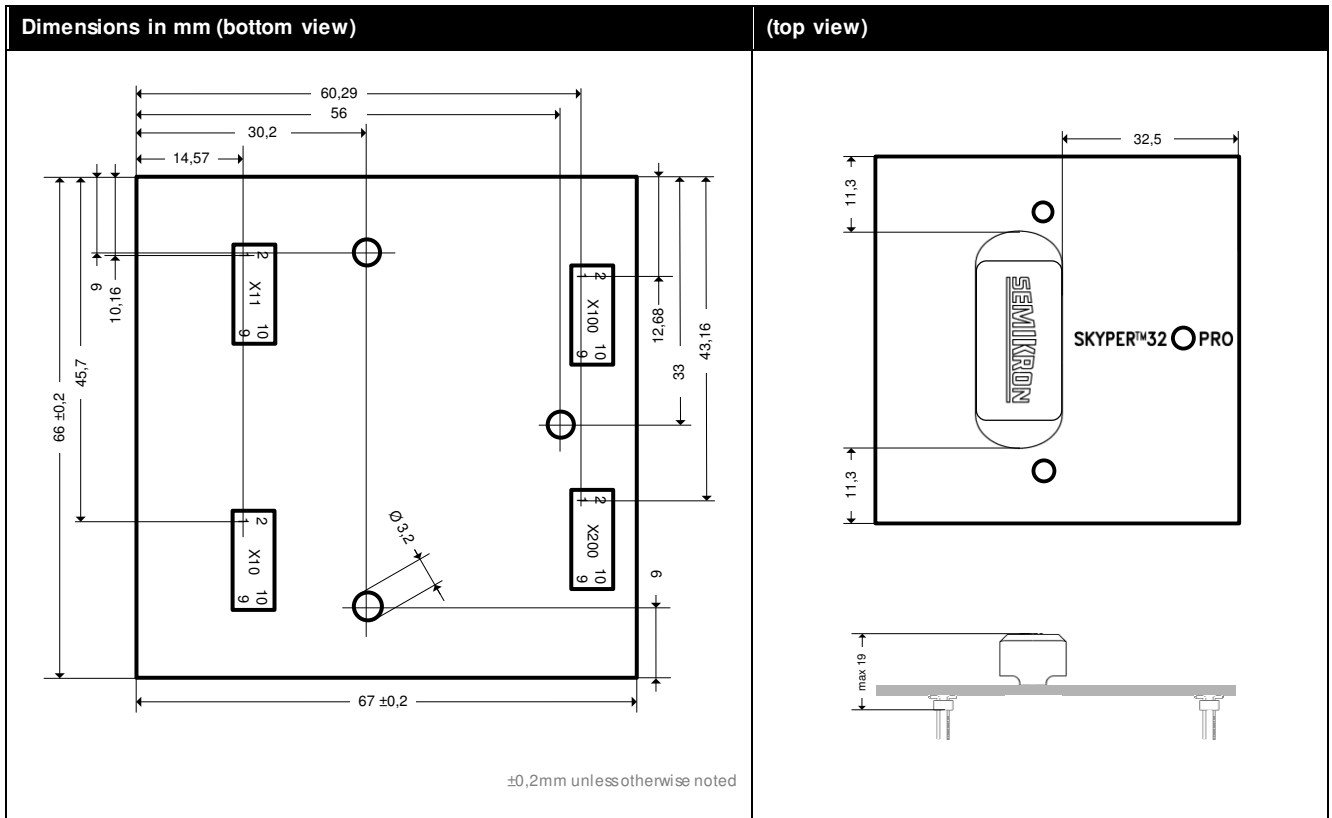
- Two output channels
- Integrated potential free power supply for secondary side
- Short Pulse Suppression (SPS)
- Under Voltage Protection (UVP) primary & secondary
- Under Voltage Reset (UVR)
- Drive interlock (dead time) top / bottom (DT) adjustable
- Dynamic Short Circuit Protection (DSCP) by  $V_{CE}$  monitoring and direct switch off
- UL recognized, ROHS
- Soft Turn-Off (STO)
- Halt Logic Signal (HLS)
- Failure Management
- External Error Input
- DC bus voltage up to 1200V
- Coated with varnish



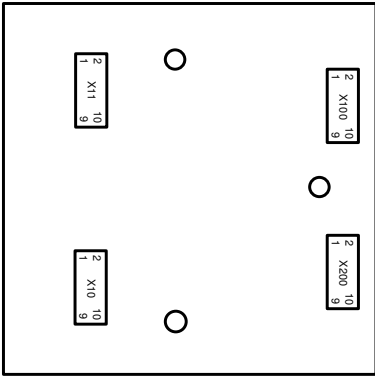
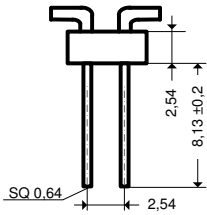
## Block diagram



## Dimensions

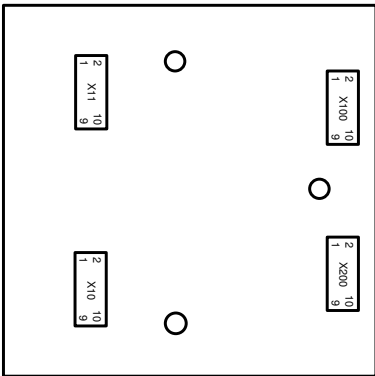
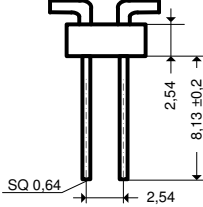


## PIN Array – Primary Side

Connectors	Connector X10 / X11 (RM2,54, 10pin)
	 <p style="text-align: right; font-size: small;">±0,25mm unless otherwise noted</p>

PIN	Signal	Function	Specification
X10:01	PRIM_nPWRFAIL_IN	Under Voltage Reset (supervisor reset to be driven by an external circuitry)	Inverted 15 V logic; 100kOhm impedance; LOW = hold; HIGH = normal operation
X10:02	reserved		
X10:03	PRIM_HALT_OUT	Driver core status output	Digital 15 V logic; max. 2mA; LOW = ready to operate; HIGH = not ready to operate
X10:04	PRIM_HALT_IN	Driver core status input	Digital 15 V logic; 100kOhm impedance; LOW = enable driver; HIGH = disable driver
X10:05	PRIM_PWR_GND	GND for power supply and GND for digital signals	
X10:06	PRIM_PWR_GND	GND for power supply and GND for digital signals	
X10:07	PRIM_TOP_IN	Switching signal input (TOP switch)	Digital 15 V logic; 100kOhm impedance; LOW = TOP switch off; HIGH = TOP switch on
X10:08	PRIM_BOT_IN	Switching signal input (BOTTOM switch)	Digital 15 V logic; 100kOhm impedance; LOW = BOT switch off; HIGH = BOT switch on
X10:09	PRIM_PWR_15P	Drive core power supply	Stabilised +15V ±4%
X10:10	PRIM_PWR_15P	Drive core power supply	Stabilised +15V ±4%
X11:01	reserved		
X11:02	reserved		
X11:03	PRIM_PWR_GND	GND for power supply and GND for digital signals	
X11:04	PRIM_PWR_GND	GND for power supply and GND for digital signals	
X11:05	PRIM_CFG_TDT2_IN	Digital adjustment of locking time	Dead time bit #2
X11:06	PRIM_CFG_SELECT_IN	Signal for neutralizing locking function	
X11:07	PRIM_CFG_TDT3_IN	Digital adjustment of locking time	Dead time bit #3
X11:08	PRIM_CFG_TDT1_IN	Digital adjustment of locking time	Dead time bit #1
X11:09	PRIM_PWR_GND	GND for power supply and GND for digital signals	
X11:10	PRIM_PWR_GND	GND for power supply and GND for digital signals	

## PIN Array – Secondary Side

Connectors	Connector X100 / X200 (RM2,54, 10pin)
	 <p style="text-align: right;">±0,25mm unless otherwise noted</p>

PIN	Signal	Function	Specification
X100:01	SEC_TOP_VCE_CFG	Input reference voltage adjustment	
X100:02	SEC_TOP_VCE_IN	Input V <sub>CE</sub> monitoring	
X100:03	SEC_TOP_15P	Output power supply	Stabilised +15V / max. 10mA <sup>1)</sup>
X100:04	SEC_TOP_ERR_IN	External error input	Voltage input; 6,6kOhm impedance; LOW = ERROR
X100:05	SEC_TOP_IGBT_ON	Switch on signal TOP IGBT	
X100:06	SEC_TOP_IGBT_OFF	Switch off signal TOP IGBT	
X100:07	SEC_TOP_GND	GND for power supply and GND for digital signals	
X100:08	SEC_TOP_GND	GND for power supply and GND for digital signals	
X100:09	SEC_TOP_IGBT_SOFTOFF	Control input for setting soft turn-off TOP IGBT	
X100:10	SEC_TOP_8N	Output power supply	Stabilised -7V / max. 10mA <sup>1)</sup>
X200:01	SEC_BOT_VCE_CFG	Input reference voltage adjustment	
X200:02	SEC_BOT_VCE_IN	Input V <sub>CE</sub> monitoring	
X200:03	SEC_BOT_15P	Output power supply	Stabilised +15V / max. 10mA <sup>1)</sup>
X200:04	SEC_BOT_ERR_IN	External error input	Voltage input; 6,6kOhm impedance; LOW = ERROR
X200:05	SEC_BOT_IGBT_ON	Switch on signal BOT IGBT	
X200:06	SEC_BOT_IGBT_OFF	Switch off signal BOT IGBT	
X200:07	SEC_BOT_GND	GND for power supply and GND for digital signals	
X200:08	SEC_BOT_GND	GND for power supply and GND for digital signals	
X200:09	SEC_BOT_IGBT_SOFTOFF	Control input for setting soft turn-off BOT IGBT	
X200:10	SEC_BOT_8N	Output power supply	Stabilised -7V / max. 10mA <sup>1)</sup>

<sup>1)</sup> The average output current of the driver will be reduced accordingly.

## Driver Performance

The driver is designed for application with half bridges or single modules and a maximum gate charge per pulse < 6,3µC. The charge necessary to switch the IGBT is mainly depending on the IGBT's chip size, the DC-link voltage and the gate voltage. This correlation is shown in module datasheets. It should, however, be considered that the driver is turned on at +15V and turned off at -7V. Therefore, the gate voltage will change by 22V during each switching procedure. Unfortunately, many datasheets do not show negative gate voltages. In order to determine the required charge, the upper leg of the charge curve may be prolonged to +22V for determination of approximate charge per switch.

The medium output current of the driver is determined by the switching frequency and the gate charge. The maximum switching frequency may be calculated with the shown equations and is limited by the average current of the driver power supply and the power dissipation of driver components.

Calculation Switching Frequency	Maximum Switching Frequency @ different Gate Charges @ T <sub>amb</sub> =25°C																						
$f_{max} = \frac{I_{out_{AVmax}}}{Q_{GE}}$ <p>f<sub>max</sub>: Maximum switching frequency *                      I<sub>out<sub>AVmax</sub></sub>: Maximum output average current                      Q<sub>GE</sub>: Gate charge of the driven IGBT</p> <p>*@ T<sub>amb</sub>=25°C</p>	<table border="1"> <caption>Approximate data for Maximum Switching Frequency vs Gate Charge</caption> <thead> <tr> <th>Gate Charge (µC)</th> <th>Switching Frequency (kHz)</th> </tr> </thead> <tbody> <tr><td>0</td><td>50</td></tr> <tr><td>1</td><td>50</td></tr> <tr><td>2</td><td>35</td></tr> <tr><td>3</td><td>25</td></tr> <tr><td>4</td><td>20</td></tr> <tr><td>5</td><td>18</td></tr> <tr><td>6</td><td>16</td></tr> <tr><td>6.3</td><td>15</td></tr> </tbody> </table>	Gate Charge (µC)	Switching Frequency (kHz)	0	50	1	50	2	35	3	25	4	20	5	18	6	16	6.3	15				
Gate Charge (µC)	Switching Frequency (kHz)																						
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6.3	15																						
Calculation Average Output Current	Average Output Current as a Function of the Ambient Temperature																						
$I_{out_{AV}} = f_{sw} \times Q_{GE}$ <p>I<sub>out<sub>AV</sub></sub>: Average output current                      f<sub>sw</sub>: Switching frequency                      Q<sub>GE</sub>: Gate charge of the driven IGBT</p>	<table border="1"> <caption>Approximate data for Average Output Current vs Ambient Temperature</caption> <thead> <tr> <th>Ambient Temperature (°C)</th> <th>Average Output Current (mA)</th> </tr> </thead> <tbody> <tr><td>0</td><td>50</td></tr> <tr><td>10</td><td>50</td></tr> <tr><td>20</td><td>50</td></tr> <tr><td>30</td><td>50</td></tr> <tr><td>40</td><td>50</td></tr> <tr><td>50</td><td>50</td></tr> <tr><td>60</td><td>50</td></tr> <tr><td>70</td><td>50</td></tr> <tr><td>80</td><td>40</td></tr> <tr><td>85</td><td>35</td></tr> </tbody> </table>	Ambient Temperature (°C)	Average Output Current (mA)	0	50	10	50	20	50	30	50	40	50	50	50	60	50	70	50	80	40	85	35
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**Please note:**

The maximum value of the switching frequency is limited to 50kHz due to switching reasons.

## Insulation

Magnetic transformers are used for insulation between gate driver primary and secondary side. The transformer set consists of pulse transformers which are used bidirectional for turn-on and turn-off signals of the IGBT and the error feedback between secondary and primary side, and a DC/DC converter. This converter provides a potential separation (galvanic separation) and power supply for the two secondary (TOP and BOT) sides of the driver. Thus, external transformers for power supply are not required.

Creepage and Clearance Distance in mm	
Primary to secondary	Min. 12,2



## Isolation Test Voltage

The isolation test voltage represents a measure of immunity to transient voltages. The maximum test voltage and time applied once between input and output, and once between output 1 and output 2 are indicated in the absolute maximum ratings. The high-voltage isolation tests and repeated tests of an isolation barrier can degrade isolation capability due to partial discharge. Repeated isolation voltage tests should be performed with reduced voltage. The test voltage must be reduced by 20% for each repeated test.

The isolation of the isolation barrier (transformer) is checked in the part. With exception of the isolation barrier, no active parts, which could break through are used. An isolation test is not performed as a series test. Therefore, the user can perform once the isolation test with voltage and time indicated in the absolute maximum ratings.

**Please note:**

An isolation test is not performed at SEMIKRON as a series test.

## Auxiliary Power Supply

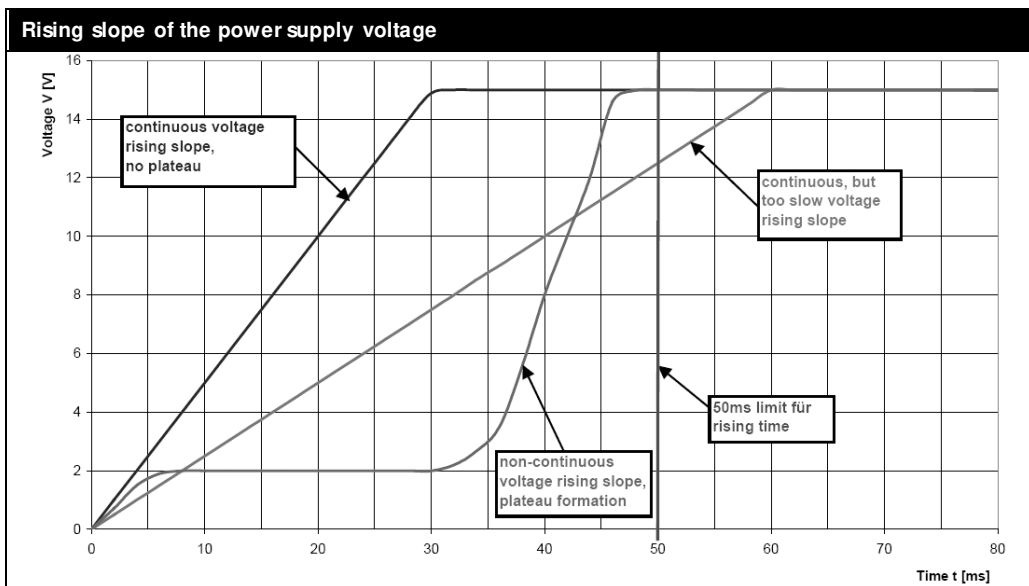
A few basic rules should be followed when dimensioning the customer side power supply for the driver. The following table shows the required features of an appropriate power supply.

Requirements of the auxiliary power supply	
Regulated power supply	+15V ±4%
Maximum rise time of auxiliary power supply	50ms
Minimum peak current of auxiliary supply	1A
Power on reset completed after	150ms

**Please note:**

Do not apply switching signals during power on reset.

The supplying switched mode power supply may not be turned-off for a short time as consequence of its current limitation. Its output characteristic needs to be considered. Switched mode power supplies with fold-back characteristic or hiccup-mode can create problems if no sufficient over current margin is available. The voltage has to rise continuously and without any plateau formation as shown in the following diagram.



If the power supply is able to provide a higher current, a peak current will flow in the first instant to charge up the input capacitances on the driver. Its peak current value will be limited by the power supply and the effective impedances (e.g. distribution lines), only.

It is recommended to avoid the paralleling of several customer side power supply units. Their different set current limitations may lead to dips in the supply voltage.

The driver is ready for operation typically 150ms after turning on the supply voltage. The driver error signal PRIM\_HOLD\_OUT and PRIM\_HOLD\_IN are operational after this time. Without any error present, the PRIM\_HOLD\_OUT signal will be reset.

To assure a high level of system safety the TOP and BOT signal inputs should stay in a defined state (OFF state, LOW) during driver turn-on time. Only after the end of the power-on-reset, IGBT switching operation shall be permitted.

## Under Voltage Reset (UVR)

The Under Voltage Reset circuit configures the driver core to hold in a reset state during power on and power off. UVR can be thought of as a supplement function to the build in power-on-reset by the user. While in reset, the driver is held in its initial condition until PRIM\_nPWRFAIL\_IN is forced into HIGH state. Once the system reset sequence completes, the driver core is ready to operate.

UVR input	Application Hints
	<p>A capacitor is connected to the input to obtain high noise immunity.</p> <p><b>Disabling of the Under Voltage Reset function (PRIM_nPWRFAIL_IN) can be achieved by no connection or connection to +15V.</b></p>

**Please note:**

Do not use PRIM\_nPWRFAIL\_IN to place the driver core into halt mode during operation.

## Under Voltage Protection (UVP) primary

The internally detected supply voltage of the driver has an under voltage protection. The table below gives an overview of the trip level.

Supply voltage	UVP level
Regulated +15V ±4%	13,5V

If the internally detected supply voltage of the driver falls below this level, the IGBTs will be switched off (IGBT driving signals set to LOW). The input side switching signals of the driver will be ignored. The error memory will be set, and the output PRIM\_HOLD\_OUT changes to the HIGH state.

## Under Voltage Protection secondary

This function monitors the rectified voltage on the secondary side. If the voltage drops, the IGBTs will be switched off (IGBT driving signal set to LOW). The input side switching signals of the driver will be ignored. The error memory will be set, and the output PRIM\_HOLD\_OUT changes to the HIGH state.

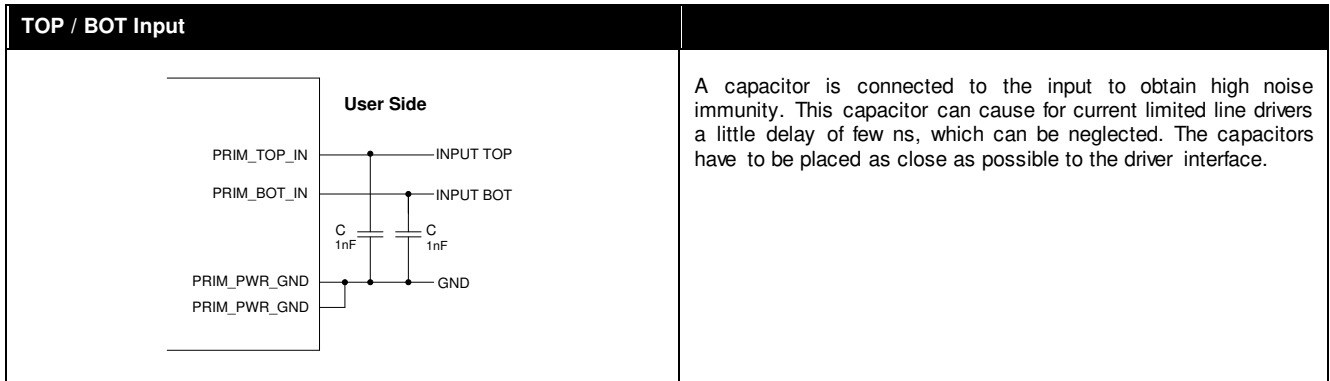
Output voltage	UVP level
Regulated +15V	12V

## Input Signals

The signal transfer to each IGBT is made with pulse transformers, used for switching on and switching off of the IGBT. The inputs have a Schmitt Trigger characteristic and a positive / active high logic (input HIGH = IGBT on; input LOW = IGBT off). It is mandatory to use circuits which switch active to +15V and 0V. Pull up and open collector output stages must not be used for TOP / BOT control signals. It is recommended choosing the line drivers according to the demanded length of the signal wires.

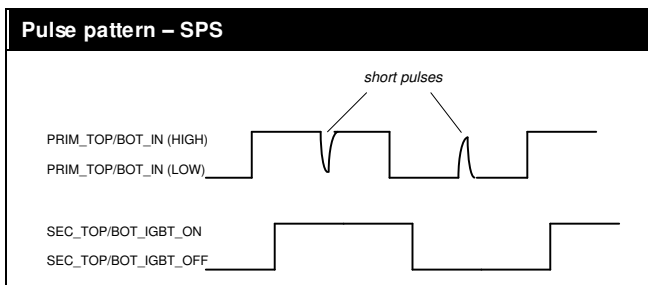
**Please note:**

It is not permitted to apply switching pulses shorter than 1µs.



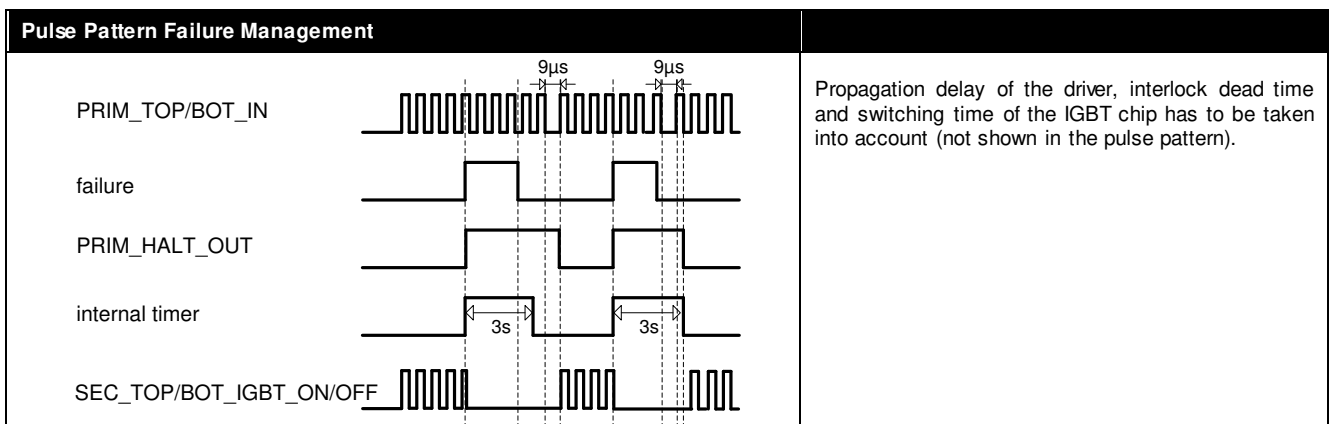
## Short Pulse Suppression (SPS)

This circuit suppresses short turn-on and off-pulses of incoming signals. This way the IGBTs are protected against spurious noise as they can occur due to bursts on the signal lines. Pulses shorter than 625ns are suppressed and all pulses longer than 750ns get through for 100% probability. Pulses with a length in-between 625ns and 750ns can be either suppressed or get through.



## Failure Management

A failure caused by PRIM\_nPWRFAIL\_IN, under voltage protection, dynamic short circuit detection or external error input will force PRIM\_HALT\_OUT into HIGH state (not ready to operate). The IGBTs will be switched off (IGBT driving signals set to LOW) and switching pulses from the controller will be not transferred to the output stage. Connected and switched off IGBTs remain turned off. At the same time an internal timer with a time constant of 3s is started. If no failure, caused by PRIM\_nPWRFAIL\_IN or under voltage protection is present anymore, a time of 3s after failure detection is passed and also TOP and BOT input signals are set to the LOW level for a period of minimum  $t_{pERRRESET} > 9\mu s$ , the driver core is ready to operate and switching pulses are transferred to the output stage. If PRIM\_HALT\_OUT is HIGH state, the external error input is not monitored. A present failure signal at external error input during PRIM\_HALT\_OUT in HIGH state is again detected after a reset signal and first transfer of TOP and BOT switching pulses to the output stage.

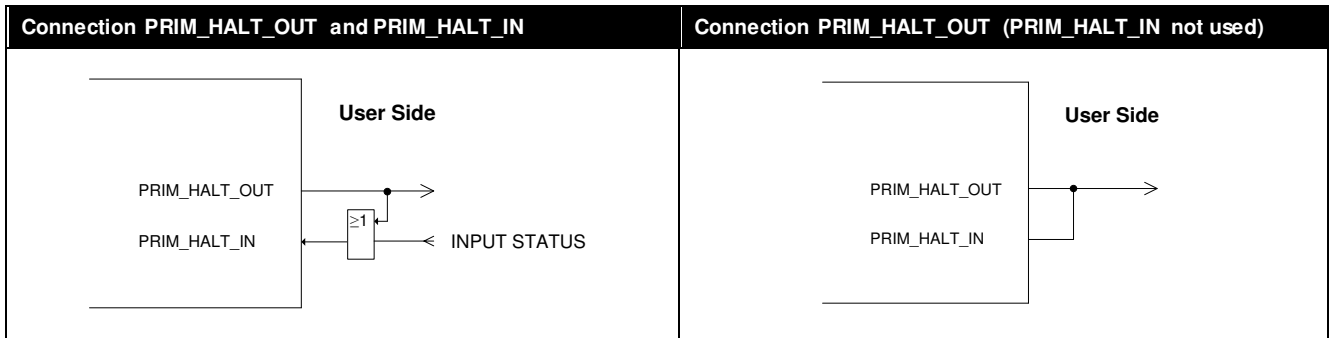


## Halt Logic Signal (HLS)

The Halt Logic Signals PRIM\_HALT\_IN and PRIM\_HALT\_OUT show and control the drive core status. The driver core is placed into halt mode by setting PRIM\_HALT\_IN into HIGH state (disable driver). This signal can gather disable signals of other hardware components for stopping operation and switching off the IGBT. A HIGH signal will set the driver core into HOLD and switching pulses from the controller will be not transferred to the output stage. The input and output have Schmitt Trigger characteristic. Pull up and open collector output stages must not be used.

**Please note:**

PRIM\_HALT\_OUT must be always connected with PRIM\_HALT\_IN. PRIM\_HALT\_OUT is not short circuit proof.

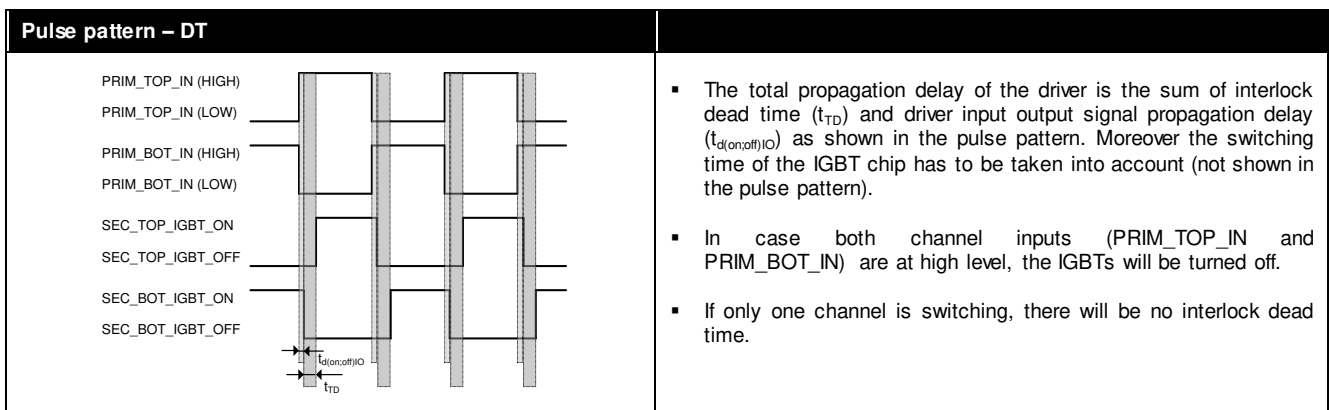


**Please note:**

A HIGH signal @ PRIM\_HALT\_IN does not generate a HIGH signal @ PRIM\_HALT\_OUT. After LOW signal @ PRIM\_HALT\_IN the gate driver is enable do operate.

## Dead Time generation (Interlock TOP / BOT) adjustable (DT)

The DT circuit prevents, that TOP and BOT IGBT of one half bridge are switched on at the same time (shoot through). The dead time is not added to a dead time given by the controller. Thus the total dead time is the maximum of "built in dead time" and "controller dead time". It is possible to control the driver with one switching signal and its inverted signal.



**Please note:**

No error message will be generated when overlap of switching signals occurs.

The dead time can be adjusted and the locking function may be neutralized as shown in the following table.

## Adjustment of Dead time / Neutralizing Locking Functions

Interlock time [μs]	PRIM_CFG_TDT1_IN	PRIM_CFG_TDT2_IN	PRIM_CDG_TDT3_IN	PRIM_CFG_SELECT_IN
1	GND	GND	open	open
1,3	GND	GND	GND	open
2	GND	open	open	open
2,3	GND	open	GND	open
3	open	GND	open	open
3,3	open	GND	GND	open
4 *	open	open	open	open
4,3	open	open	GND	open
no interlock	open	open	open	GND

\* Factory setting

### Please note:

The dead time has to be longer than the turn-off delay time of the IGBT in any case. This is to avoid that one IGBT is turned on before the other one is not completely discharged. If the dead time is too short, the heat generated by the short circuit current may destroy the module in the event of a short circuit in top or bottom arm.

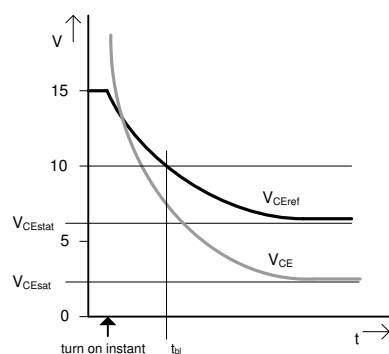
The average output current is available at each output channel. It is not possible to interconnect the output channels to achieve a higher average output current by neutralizing the locking function.

## Dynamic Short Circuit Protection by $V_{CEsat}$ monitoring / de-saturation monitoring (DSCP)

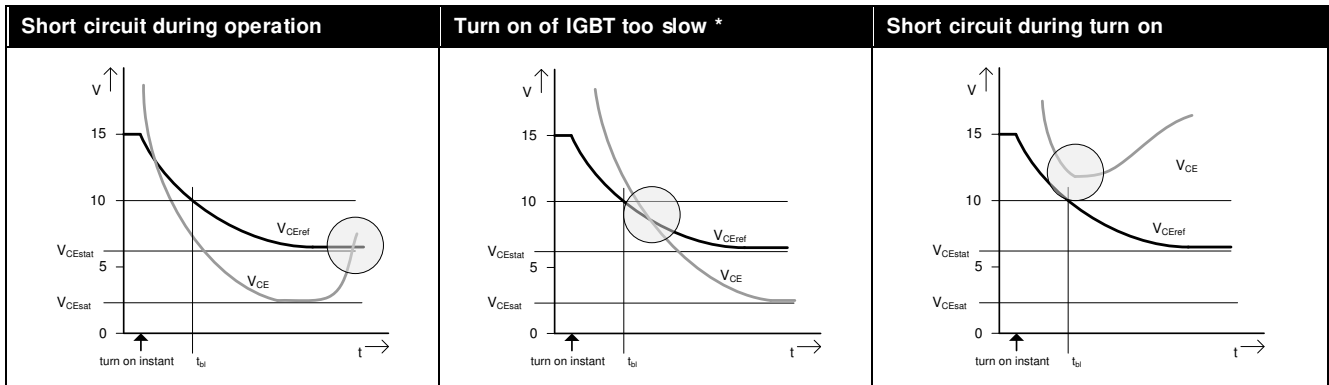
The DSCP circuit is responsible for short circuit sensing. It monitors the collector-emitter voltage  $V_{CE}$  of the IGBT during its on-state. Due to the direct measurement of  $V_{CEsat}$  on the IGBT's collector, the DSCP circuit switches off the IGBTs and an error is indicated.

The reference voltage  $V_{CEref}$  may dynamically be adapted to the IGBTs switching behaviour. Immediately after turn-on of the IGBT, a higher value is effective than in steady state. This value will, however, be reset, when the IGBT is turned off.  $V_{CEstat}$  is the steady-state value of  $V_{CEref}$  and is adjusted to the required maximum value for each IGBT by an external resistor  $R_{CE}$ . It may not exceed 10V. The time constant for the delay (exponential shape) of  $V_{CEref}$  may be controlled by an external capacitor  $C_{CE}$ , which is connected in parallel to  $R_{CE}$ . It controls the blanking time  $t_{bl}$  which passes after turn-on of the IGBT before the  $V_{CEsat}$  monitoring is activated. This makes an adaptation to any IGBT switching behaviour possible.

### Reference Voltage ( $V_{CEref}$ ) Characteristic



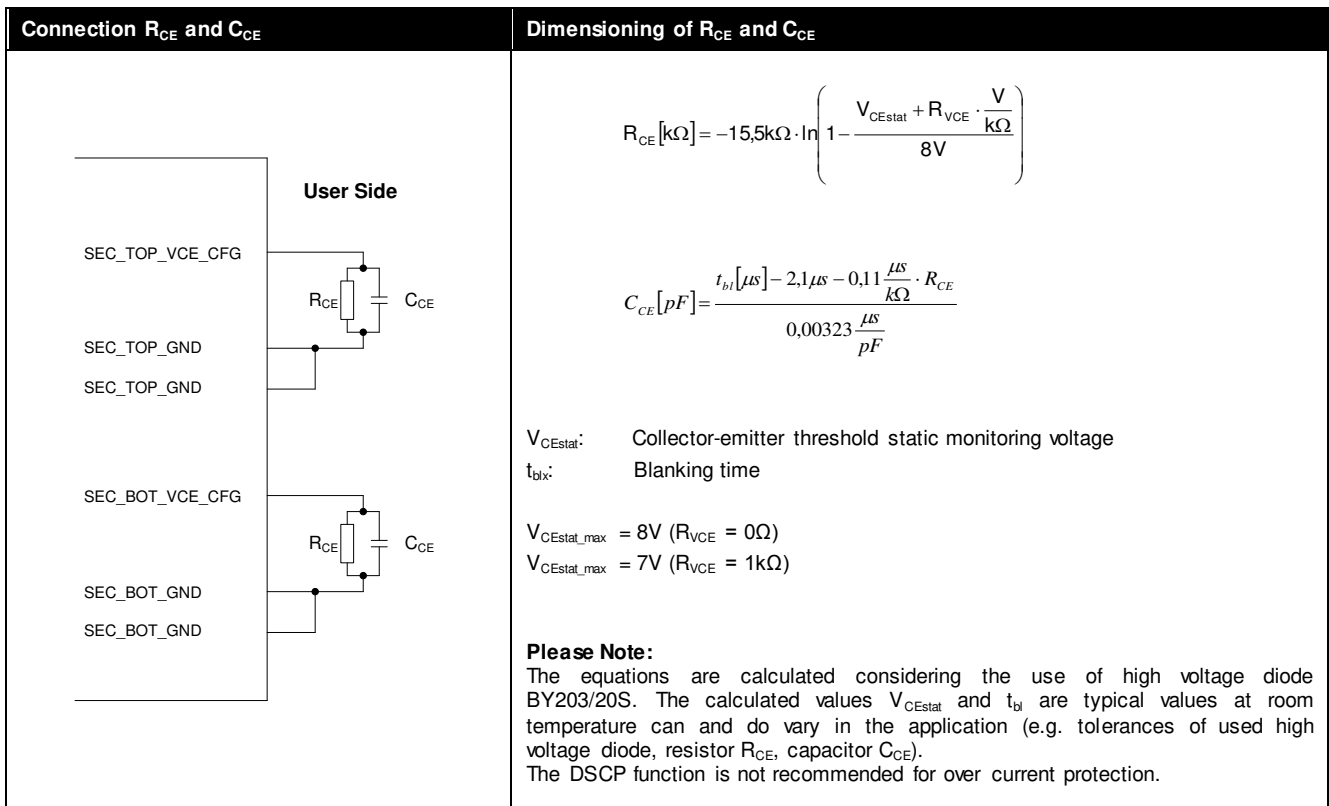
After  $t_{bl}$  has passed, the  $V_{CE}$  monitoring will be triggered as soon as  $V_{CE} > V_{CEref}$  and will turn off the IGBT. The error memory will be set, and the output PRIM\_HOLD\_OUT changes to the HIGH state. Possible failure modes are shown in the following pictures.



\* or adjusted blanking time too short

## Adjustment of DSCP

The external components  $R_{CE}$  and  $C_{CE}$  are applied for adjusting the steady-state threshold the blanking time.

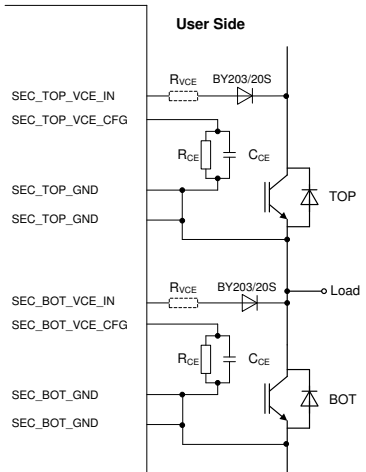


## Application hints

If the DSCP function is not used, for example during the experimental phase, SEC\_TOP\_VCE\_IN must be connected with SEC\_TOP\_GND for disabling SCP @ TOP side and SEC\_BOT\_VCE\_IN must be connected with SEC\_BOT\_GND for disabling SCP @ BOT side.

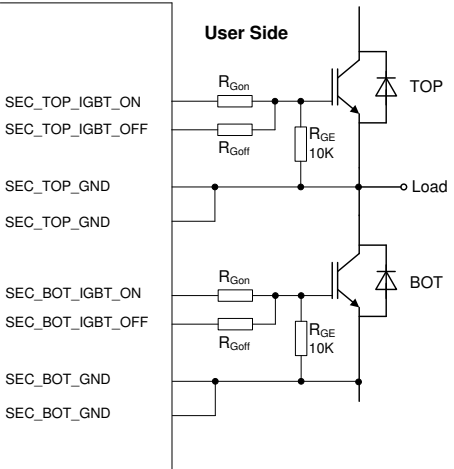
## High Voltage Diode for DSCP

The high voltage diode blocks the high voltage during IGBT off state. The connection of this diode between driver and IGBT is shown in the following schematic.

Connection High Voltage Diode	Characteristics
 <p>The diagram shows two IGBTs, labeled TOP and BOT, connected to a common Load. Each IGBT has a collector (C), emitter (E), and gate (G) terminal. The collector of each IGBT is connected to the Load through a resistor <math>R_{VCE}</math>. A diode (BY203/20S) is connected between the collector and the emitter of each IGBT. The driver side has terminals for <math>SEC\_TOP\_VCE\_IN</math>, <math>SEC\_TOP\_VCE\_CFG</math>, <math>SEC\_TOP\_GND</math>, <math>SEC\_BOT\_VCE\_IN</math>, <math>SEC\_BOT\_VCE\_CFG</math>, <math>SEC\_BOT\_GND</math>, and <math>SEC\_BOT\_GND</math>.</p>	<ul style="list-style-type: none"> <li>Reverse blocking voltage of the diode shall be higher than the used IGBT.</li> <li>Reverse recovery time of the fast diode shall be lower than <math>V_{CE}</math> rising of the used IGBT.</li> <li>Forward voltage of the diode: 1,5V @ 2mA forward current (<math>T_j=25^\circ C</math>).</li> </ul> <p><b>A collector series resistance <math>R_{VCE}</math> (1k<math>\Omega</math> / 0,4W) must be connected for 1700V IGBT operation.</b></p>

## Gate resistors

The output transistors of the driver are MOSFETs. The sources of the MOSFETs are separately connected to external terminals in order to provide setting of the turn-on and turn-off speed of each IGBT by the external resistors  $R_{Gon}$  and  $R_{Goff}$ . As an IGBT has input capacitance (varying during switching time) which must be charged and discharged, both resistors will dictate what time must be taken to do this. The final value of the resistance is difficult to predict, because it depends on many parameters as DC link voltage, stray inductance of the circuit, switching frequency and type of IGBT.

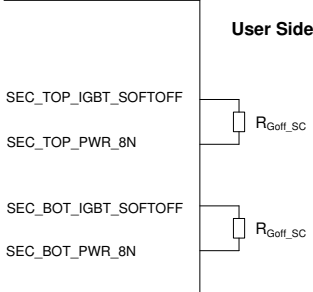
Connection $R_{Gon}$ , $R_{Goff}$	Application Hints
 <p>The diagram shows two IGBTs, labeled TOP and BOT, connected to a common Load. Each IGBT has a collector (C), emitter (E), and gate (G) terminal. The emitter of each IGBT is connected to the Load. A gate resistor <math>R_{GE}</math> (10K) is connected between the gate and emitter of each IGBT. Gate resistors <math>R_{Gon}</math> and <math>R_{Goff}</math> are connected between the driver and the gate terminal. The driver side has terminals for <math>SEC\_TOP\_IGBT\_ON</math>, <math>SEC\_TOP\_IGBT\_OFF</math>, <math>SEC\_TOP\_GND</math>, <math>SEC\_BOT\_IGBT\_ON</math>, <math>SEC\_BOT\_IGBT\_OFF</math>, <math>SEC\_BOT\_GND</math>, and <math>SEC\_BOT\_GND</math>.</p>	<p>The gate resistor influences the switching time, switching losses, <math>dv/dt</math> behaviour, etc. and has to be selected very carefully. Due to this influence a general value for the gate resistors cannot be recommended. The gate resistor has to be optimized according to switching behaviour and over voltage peaks within the specific circuitry.</p> <p>By increasing <math>R_{Gon}</math> the turn-on speed will decrease. The reverse peak current of the free-wheeling diode will diminish.</p> <p>By increasing <math>R_{Goff}</math> the turn-off speed of the IGBT will decrease. The inductive peak over voltage during turn-off will diminish.</p> <p>In order to ensure locking of the IGBT even when the driver supply voltage is turned off, a resistance (<math>R_{GE}</math>) has to be integrated.</p>

### Please note:

Do not connect the terminals  $SEC\_TOP\_IGBT\_ON$  with  $SEC\_TOP\_IGBT\_OFF$  and  $SEC\_BOT\_IGBT\_ON$  with  $SEC\_BOT\_IGBT\_OFF$ , respectively.

## Soft Turn-Off (STO)

In the event of short circuit, the STO circuit increases the resistance in series with  $R_{Goff}$  and turns-off the IGBT at lower speed. This produces smaller voltage spike above the collector emitter of the IGBT by reducing the di/dt value. Because in short-circuit conditions the IGBT's peak current increases and some stray inductance is always present in power circuits, it must fall to zero in a longer time than at normal operation. The soft turn-off time can be adjusted by connection an external resistor  $R_{Goff\_SC}$ .

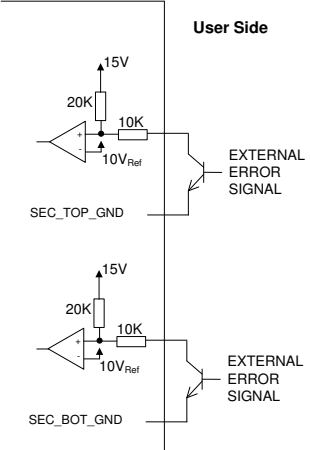
Connection $R_{Goff\_SC}$	Application Hints
	<p>The turn-off behaviour and over voltage peaks depends on DC link voltage, stray inductance of the power circuits, type of IGBT, etc. and has to be selected according the specific application. Due to this influence a general value for <math>R_{Goff\_SC}</math> cannot be recommended. The resistor has to be selected according to the behaviour of the specific circuitry.</p> <p>The soft turn-off time is limited to 10µs. After this time the output stage turn-off with used <math>R_{Goff}</math>.</p> <p>Disabling of Soft Turn-Off can be achieved by <math>R_{Goff\_SC} = 0\Omega</math> or wire bridge.</p>

**Please note:**

The soft turn-off function is no complete protection from induced over voltage in the event of short-circuit turn-off. A HIGH signal at PRIM\_HALT\_IN does not activate a soft turn-off.

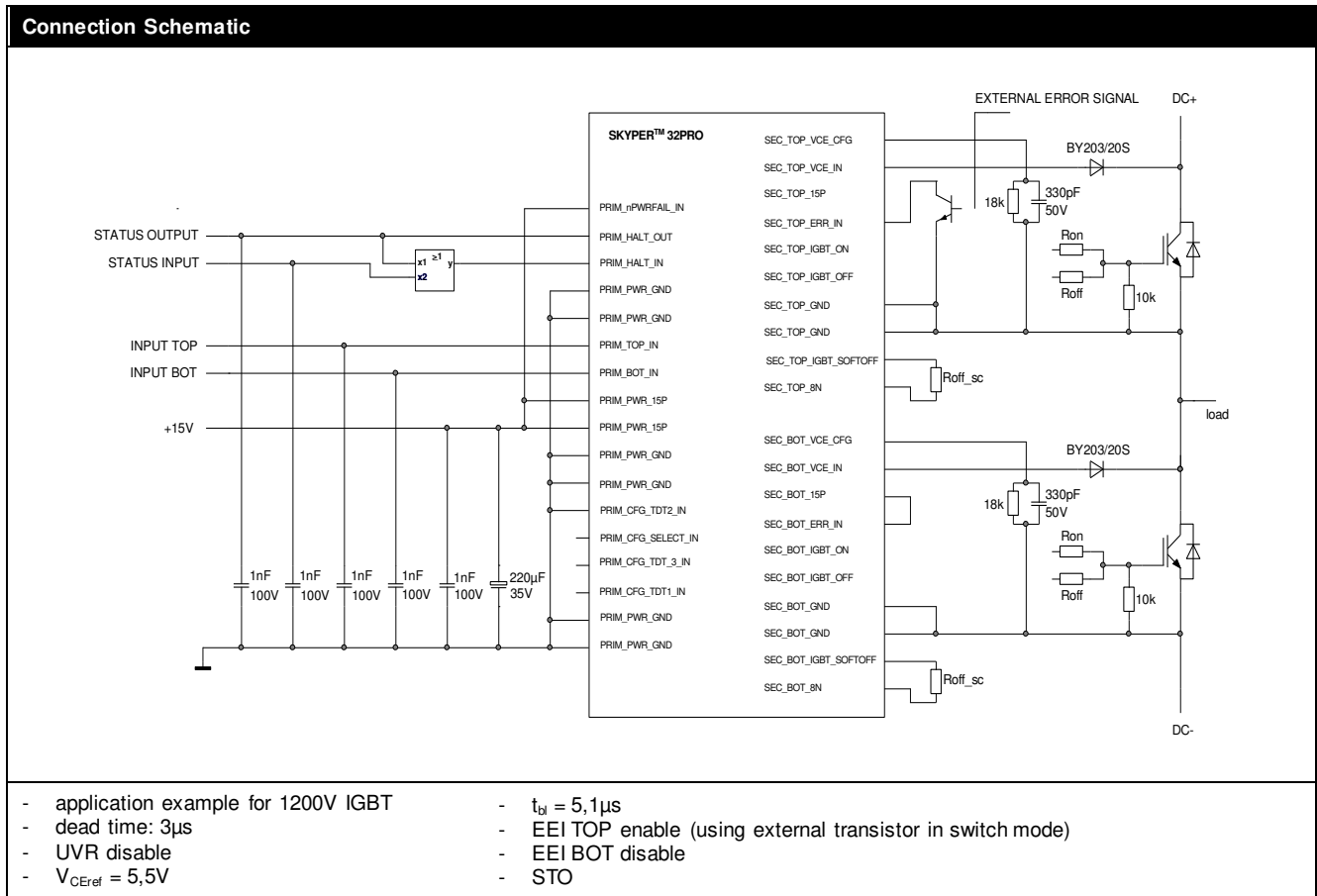
## External Error Input (EEI)

The external error inputs on the secondary side (high potential) of the gate driver can be used for external fault signals from e. g. an over current protection circuit or over temperature protection circuit to place the gate driver into halt mode. Disabling of this function can be achieved by no connection or connection to +15V (e. g. SEC\_TOP\_15P, SEC\_BOT\_15P to SEC\_TOP\_ERR\_IN and SEC\_BOT\_ERR\_IN). It is possible to use only one error input.

Connection EEI	
	<p>Connection example with using an external transistor in switch mode.</p>



## Application Example



## Mounting Notes

Soldering Hints	Finished Hole & Pad Size in mm
<p>The temperature of the solder must not exceed 260°C, and solder time must not exceed 10 seconds.</p> <p>The ambient temperature must not exceed the specified maximum storage temperature of the driver.</p> <p>The solder joints should be in accordance to IPC A 610 Revision D (or later) - Class 3 (Acceptability of Electronic Assemblies) to ensure an optimal connection between driver core and printed circuit board.</p>	<p>Ø 1,1 ±0,05</p> <p>pad size: min. 1,8</p>

**Please note:**

The driver is not suited for hot air reflow or infrared reflow processes.

The connection between driver core and printed circuit board should be mechanical reinforced by using support posts.

Use of Support Posts	
	<p>Product information of suitable support posts and distributor contact information is available at e.g. <a href="http://www.richco-inc.com">http://www.richco-inc.com</a> (e.g. series DLMSPM, LCBST).</p> <p>When using the support posts the support post length has to be longer than 12,4mm.</p>

**Please note:**

The use of aggressive materials in cleaning process of driver core may be detrimental for the device parameters.

### Environmental Conditions

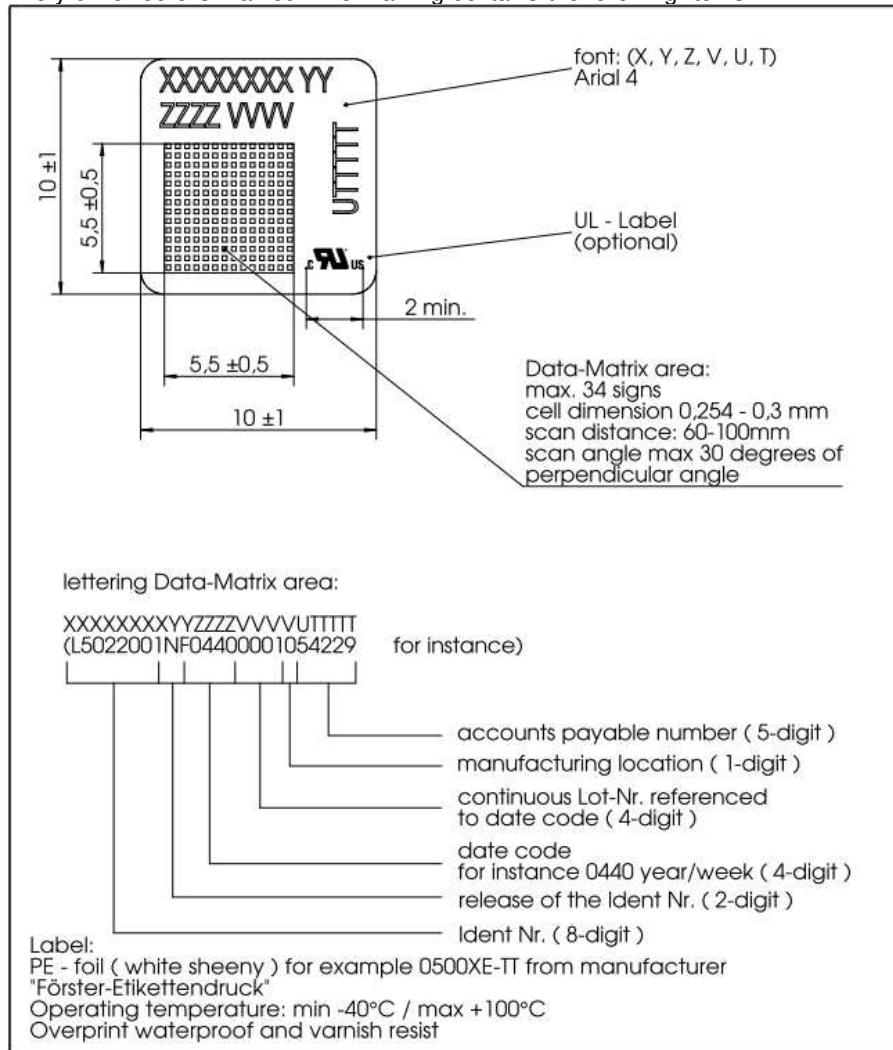
The driver core is type tested under the environmental conditions below.

Conditions	Values (max.)
Vibration	Sinusoidal sweep 20Hz ... 500Hz, 5g, 26 sweeps per axis (x, y, z) - Tested acc. IEC 68-2-6 - Connection between driver core and printed circuit board mechanical reinforced by using support posts.
Shock	Half-sinusoidal pulse, 5g, shock width 18ms, 3 shocks in each direction ( $\pm x$ , $\pm y$ , $\pm z$ ), 18 shocks in total - Tested acc. IEC 68-2-27 - Connection between driver core and printed circuit board mechanical reinforced by using support posts.

The characteristics and further environmental conditions are indicated in the data sheet.

## Marking

Every driver core is marked. The marking contains the following items.



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